# RICOH

# 300 mA, 42 V Voltage Regulator with High Noise Immunity

No. EA-527-201014

#### OVERVIEW

The R1526x is a voltage regulator featuring 300mA output current and 42 V maximum input voltage. Since this device has excellent noise immunity to external electromagnetic interference, it is suitable for use in environments where electromagnetic waves may cause malfunctions.

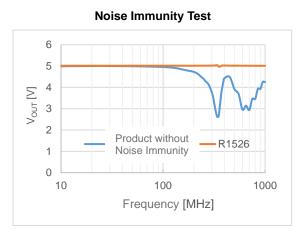
#### **KEY BENEFITS**

- Excellent noise immunity. Refer to Noise Immunity Test in Typical Characteristics. •
- Pin configuration considering functional safety •

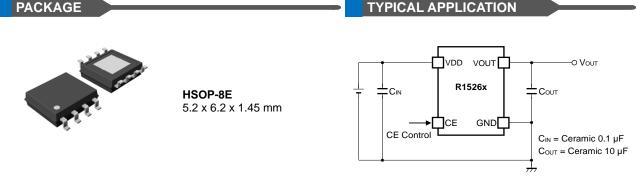
#### **KEY SPECIFICATIONS**

- Input Voltage Range (Maximum Rating): 3.5 V to 42 V (50 V)
- Operating temperature range: -40°C to 105°C
- Standby Current: Typ. 0.1 µA
- Dropout Voltage: Max. 0.5 V (IOUT = 200 mA, VOUT = 5.0 V)
- Output Voltage: 1.8 V to 9.0 V (in 0.1 V step) •
- Output Voltage Accuracy:  $\pm 0.6$  % (Ta = 25°C) ±1.6 % (-40°C ≤ Ta ≤ 105°C)
- Line Regulation: Typ. 0.01%/V ( $V_{SET}$  + 1 V  $\leq$  V<sub>IN</sub>  $\leq$  42 V)
- Short-circuit Protection: Limit at Typ. 100 mA •
- Overcurrent Protection: Limit at Typ. 450 mA
- Thermal Shutdown: Detection Temperature. Typ. 160°C •
- Output capacitor:  $C_{OUT} \ge 10 \ \mu F$
- Ripple Rejection: Typ. 50 dB (f = 100 Hz)









#### APPLICATIONS

- Power source for home appliances such as refrigerators, rice cookers and electric hot-water pots.
- Power source for notebook PCs, digital TVs, cordless phones, and private LAN systems.
- Power source for office equipment machines such as copiers, printers, facsimiles, scanners and projectors.

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# **SELECTION GUIDE**

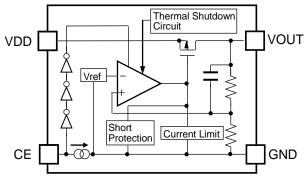
The set output voltage is user-selectable.

## **Selection Guide**

Product Name	Package	Quantity per Reel	Pb Free	Halogen Free
R1526Sxx1B-E2-FE	HSOP-8E	1,000 pcs	Yes	Yes

xx: Specify the set output voltage (V<sub>SET</sub>)
1.8 V (18) to 9.0 V (90) in 0.1 V step
Refer to *Product-specific Electrical Characteristics* for details.

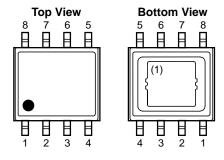
# **BLOCK DIAGRAM**



R1526x Block Diagram

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# **PIN DESCRIPTIONS**

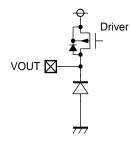


# **HSOP-8E Pin Configuration**

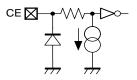
#### **HSOP-8E** Pin Descriptions

Pin No.	Pin Name	Description
1	VOUT	Output Pin
2	NC <sup>(2)</sup>	No Connection
3	NC <sup>(2)</sup>	No Connection
4	CE	Chip Enable Pin (Active-high)
5	GND <sup>(3)</sup>	Ground Pin
6	GND <sup>(3)</sup>	Ground Pin
7	NC <sup>(2)</sup>	No Connection
8	VDD	Input Pin

#### **Pin Equivalent Circuit Diagrams**



**VOUT Pin Equivalent Circuit Diagram** 



CE Pin Equivalent Circuit Diagram

<sup>&</sup>lt;sup>(1)</sup> The tab on the bottom of the package is substrate level (GND). The tab must be connected to the ground plane on the board.

<sup>&</sup>lt;sup>(2)</sup> NC pin should be set to "Open".

<sup>&</sup>lt;sup>(3)</sup> GND pins should be connected together when mounted on a board.

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# **ABSOLUTE MAXIMUM RATINGS**

## **Absolute Maximum Ratings**

Symbol	Parameter	Rating	Unit
Vin	VIN Pin Input Voltage	-0.3 to 50	V
Vin	VIN Pin Peak Voltage <sup>(1)</sup>	60	V
VCE	CE Pin Input Voltage	-0.3 to 50	V
V <sub>CE</sub>	CE Pin Peak Voltage (1)	60	V
Vout	VOUT Pin Voltage	$-0.3$ to V <sub>IN</sub> + 0.3 $\leq$ 50	V
Іоит	Output Current	500	mA
PD	Power Dissipation	Refer to Apper "Power Dissipat	
Tj	Junction Temperature Range	-40 to 125	°C
Tstg	Storage Temperature Range	-55 to 125	°C

## ABSOLUTE MAXIMUM RATINGS

Electronic and mechanical stress momentarily exceeded absolute maximum ratings may cause permanent damage and may degrade the lifetime and safety for both device and system using the device in the field. The functional operation at or over these absolute maximum ratings is not assured.

# **RECOMMENDED OPERATING CONDITIONS**

#### **Recommended Operating Conditions**

Symbol	Parameter	Rating	Unit
VIN	Operating Input Voltage	3.5 to 42	V
Та	Operating Temperature Range	-40 to 105	°C

#### **RECOMMENDED OPERATING CONDITIONS**

All of electronic equipment should be designed that the mounted semiconductor devices operate within the recommended operating conditions. The semiconductor devices cannot operate normally over the recommended operating conditions, even if they are used over such conditions by momentary electronic noise or surge. And the semiconductor devices may receive serious damage when they continue to operate over the recommended operating conditions.

<sup>(1)</sup> Duration time: within 200 ms

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# ELECTRICAL CHARACTERISTICS

 $V_{IN} = 14 \text{ V}, V_{CE} = V_{IN}$ , unless otherwise specified.

The specifications surrounded by  $\square$  are guaranteed by design engineering at  $-40^{\circ}C \le Ta \le 105^{\circ}C$ .

<u>R1526x-l</u>	526x-FE Electrical Characteristics (Ta = 25°C)						
Symbol	Parameter	Condi	tions	Min.	Тур.	Max.	Unit
Iss	Supply Current	$V_{IN} = 14 \text{ V}, I_{OUT} = 0 \text{ m/}$	Ą		32	55	μA
Istandby	Standby Current	$V_{\text{IN}} = 42 \text{ V}, \text{ V}_{\text{CE}} = 0 \text{ V}$			0.1	2.0	μA
Vout	Output Voltage	8 $V^{(1)} \le V_{IN} \le 16 V$ ,	Ta = 25°C	×0.994		×1.006	V
001	Oulput Voltage	louт = 1 mA	-40°C ≤ Ta ≤ 105°C	×0.984		×1.016	v
			$1.8 \text{ V} \le \text{V}_{\text{SET}} \le 2.8 \text{ V}$	-5		45	
		$V_{IN} = V_{SET} + 2.0 V,$ 1 mA ≤ $I_{OUT} \le 100 \text{ mA}$	$2.8 \text{ V} < \text{V}_{\text{SET}} \leq 5.4 \text{ V}$	-5		40	
$\Delta V_{OUT}$	Load Regulation <sup>(2)</sup>		$5.4 \text{ V} < \text{V}_{\text{SET}} \le 9.0 \text{ V}$	-5		72	mV
/∆Iout			$1.8~V \le V_{\text{SET}} \le 2.8~V$	-5		68	IIIV
	$V_{IN} = V_{SET} + 2.0 V,$ 1 mA ≤ $I_{OUT}$ ≤ 300 mA	$2.8 \text{ V} < \text{V}_{\text{SET}} \leq 5.4 \text{ V}$	-5		60		
			$5.4 \text{ V} < \text{V}_{\text{SET}} \le 9.0 \text{ V}$	-5		108	
$\Delta V_{OUT}$	Line Regulation <sup>(3)</sup>	V <sub>SET</sub> +1V <sup>(4)</sup> ≤ V <sub>IN</sub> ≤42V,	$1.8 \text{ V} \le \text{V}_{\text{SET}} \le 2.8 \text{ V}$	-30		30	mV
$/\Delta V_{IN}$		I <sub>OUT</sub> = 1 mA	$2.8 \text{ V} < \text{V}_{\text{SET}} \leq 9.0 \text{ V}$	-0.02		0.02	%/V
			$1.8 \text{ V} \le \text{V}_{\text{SET}} \le 2.4 \text{ V}$		1.73	1.76	
			$2.4 \text{ V} < \text{V}_{\text{SET}} \leq 2.8 \text{ V}$		0.75	1.35	
$V_{DIF}$	Dropout Voltage (5)	I <sub>OUT</sub> = 300 mA	$2.8 \text{ V} < \text{V}_{\text{SET}} \leq 5.0 \text{ V}$		0.71	1.23	V
			$5.0 \text{ V} < \text{V}_{\text{SET}} \le 8.0 \text{ V}$		0.40	0.74	
			$8.0 \text{ V} < \text{V}_{\text{SET}} \leq 9.0 \text{ V}$		0.35	0.65	
ILIM	Output Current Limit	$V_{IN} = V_{SET} + 3.0 V$		300	450		mA
Isc	Short-circuit Current	V <sub>IN</sub> = 3.5 V, V <sub>OUT</sub> = 0 V			100		mA
VCEH	CE Pin Input Voltage, High			2.0		42	V
V <sub>CEL</sub>	CE Pin Input Voltage, Low	V <sub>IN</sub> = 42 V				1.0	V
IPD	CE Pull-down Current	$V_{IN} = 42 \text{ V}, \text{ V}_{CE} = 2 \text{ V}$			0.2	0.6	μA

All parameters are tested under the pulse load condition (Tj  $\approx$  Ta = 25°C).

 $<sup>^{(1)}</sup>$  When V<sub>SET</sub> > 7 V, V<sub>IN</sub> = V<sub>SET</sub> + 1 V

<sup>&</sup>lt;sup>(2)</sup> Output voltage change amount when 1 mA  $\leq$  I<sub>OUT</sub>  $\leq$  100 mA and 1 mA  $\leq$  I<sub>OUT</sub>  $\leq$  300 mA, ∠Vout /∠Iout = Vout (@ Iout = 100 mA) - Vout (@ Iout = 1 mA) or

<sup>∠</sup>Vout /∠lout = Vout (@ lout = 300 mA) - Vout (@ lout = 1 mA)

 $<sup>^{(3)}</sup>$  Output voltage change amount when V\_{SET} +1V  $\leq$  V\_{IN}  $\leq$  42 V,

in case V<sub>SET</sub>  $\leq$  2.8 V,  $\angle$ V<sub>OUT</sub>  $\angle$ V<sub>IN</sub> = V<sub>OUT</sub> (@V<sub>IN</sub> = 42 V) - V<sub>OUT</sub> (@V<sub>IN</sub> = V<sub>SET</sub> + 1 V) or

in case V<sub>SET</sub> > 2.8 V, ∠V<sub>OUT</sub> /∠V<sub>IN</sub> = (V<sub>OUT</sub> (@V<sub>IN</sub> = 42 V) - V<sub>OUT</sub> (@V<sub>IN</sub> = V<sub>SET</sub> + 1 V)) / (42 - (V<sub>SET</sub> + 1)) / V<sub>SET</sub> x 100 <sup>(4)</sup> When  $V_{SET} \le 2.5 \text{ V}$ ,  $V_{IN} = 3.5 \text{ V}$ .

<sup>&</sup>lt;sup>(5)</sup> Dropout voltage is defined as the minimum value of the difference between the input and output voltages in order to supply a regulated output voltage with the specified load current.

(Ta = 25°C)

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The specifications surrounded by  $\square$  are guaranteed by design engineering at -40°C  $\leq$  Ta  $\leq$  105°C.

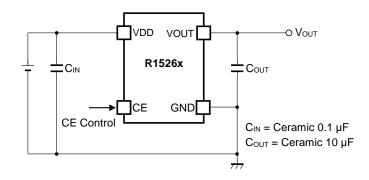
R1526x (-FE) Product-specific Electrical Characteristics	
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Product name	v <sub>оυт</sub> (V) roduct name (Ta = 25°C)		(−40°(	V <sub>о∪т</sub> (V) (−40°С ≤ Та ≤ 105°С)			Vdif (V)	
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	TYP.	MAX.
R1526x018x	1.7892	1.80	1.8108	1.7712	1.80	1.8288	1.73	1.76
R1526x025x	2.4850	2.50	2.5150	2.4600	2.50	2.5400	0.75	4.25
R1526x028x	2.7832	2.80	2.8168	2.7552	2.80	2.8448	0.75	1.35
R1526x030x	2.9820	3.00	3.0180	2.9520	3.00	3.0480		
R1526x033x	3.2802	3.30	3.3198	3.2472	3.30	3.3528	0.71	1.23
R1526x034x	3.3796	3.40	3.4204	3.3456	3.40	3.4544		
R1526x050x	4.9700	5.00	5.0300	4.9200	5.00	5.0800		
R1526x055x	5.4670	5.50	5.5330	5.4120	5.50	5.5880		
R1526x060x	5.9640	6.00	6.0360	5.9040	6.00	6.0960		
R1526x064x	6.3616	6.40	6.4384	6.2976	6.40	6.5024	0.40	0.74
R1526x075x	7.4550	7.50	7.5450	7.3800	7.50	7.6200		
R1526x080x	7.9520	8.00	8.0480	7.8720	8.00	8.1280		
R1526x085x	8.4490	8.50	8.5510	8.3640	8.50	8.6360	0.35	0.65
R1526x090x	8.9460	9.00	9.0540	8.8560	9.00	9.1440	0.55	0.65

Product name		о <mark>от (mV)</mark> т <b>≤ 100 mA)</b>		loυτ (mV) τ ≤ 300 mA)	ΔVου	r/ΔVin
	MIN.	MAX.	MIN.	MAX.	MIN.	MAX.
R1526x018x						
R1526x025x	-5	45	-5	68	<u>-30</u> (mV)	<u>30</u> (mV)
R1526x028x					(110)	(1117)
R1526x030x						
R1526x033x	-5	40	-5	60		
R1526x034x				00		
R1526x050x						
R1526x055x						
R1526x060x					-0.02 (%/V)	0.02 (%/V)
R1526x064x					(70/ V)	(70/V)
R1526x075x	-5	72	-5	108		
R1526x080x						
R1526x085x						
R1526x090x						

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# **TYPICAL APPLICATION CIRCUIT**



# **R1526x Typical Application Circuit**

## **Component examples**

Symbol	Capacitance	Tolerance	Voltage resistance	Temperature characteristics
CIN	0.1 µF	±10%	50 V	X7R
Соит	10 µF	±10%	50 V	X7S

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# THEORY OF OPERATION

# **Thermal Shutdown Function**

When the junction temperature exceeds the thermal shutdown detection temperature (Typ.160°C), R1526x goes into standby state and suppresses its self-heating. When the junction temperature falls below the thermal shutdown release temperature (Typ.135°C), this device becomes active.

# **Chip Enable Function**

By inputting "High" and "Low" to the CE pin, R1526x can be set to active or standby state. The CE pin is pulled down with a constant current of Typ. 0.2  $\mu$ A inside the IC. If the chip enable function is not needed, connect the CE pin directly to the VDD pin. R1526x can apply a voltage to the CE pin even when no voltage is applied to VDD pin.

# **TECHNICAL NOTES**

The performance of a power source circuit using this device is highly dependent on a peripheral circuit. A peripheral component or the device mounted on PCB should not exceed a rated voltage, a rated current or a rated power. When designing a peripheral circuit, please be fully aware of the following points.

# **Phase Compensation**

R1526x uses the output capacitor capacitance and equivalent series resistance (ESR) for phase compensation, to secure stable operation even when the load current is varied. For this purpose, make sure to use an output capacitor ( $C_{OUT}$ ) of 10 µF or more as close as possible to the VOUT pin. Since the output may oscillate depending on the ESR, select a low ESR capacitor with reference to *the series equivalent resistance vs. output current* characteristics in the datasheet. In addition, Make the power supply and GND lines sufficient. Connect a capacitor ( $C_{IN}$ ) of 0.1 µF or more between the VDD pin and GND, and keep the wiring as short as possible.

# Behavior below the minimum operating voltage

When  $V_{SET} \le 2.8$  V and the power supply voltage is below the recommended operating voltage, the output voltage may become unstable and exceed the set output voltage of LDO. To avoid this behavior at power-on, turn on the voltage of both VDD and CE pins at a slew rate of 35 V/ms or more when both pins are turned on at the same time. When turning on the VDD pin at a slew rate of 35 V/ms or less, change the CE pin from "Low" to "High" after the power supply voltage exceeds 3.5 V.

To avoid this behavior at power-off, turn off the voltage of both VDD and CE pins at a steeper slew rate than -35 V/ms when both pins are turned off at the same time.

When turning off the VDD pin at a slower slew rate than -35 V/ms, change the CE pin from "High" to "Low" before the power supply voltage falls below 3.5 V.

# **Thermal Shutdown Function**

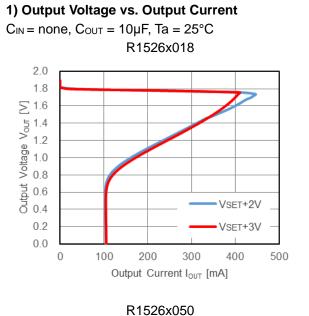
The thermal shutdown function prevents the IC from fuming and ignition but does not ensure the IC's reliability or keep the IC below the absolute maximum ratings. The thermal shutdown function does not operate on the heat generated by other than the normal IC operation such as latch-up and overvoltage application.

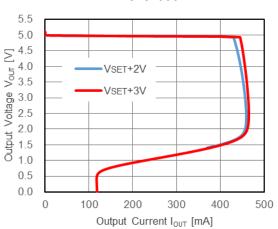
The thermal shutdown function operates in a state over the absolute maximum ratings, therefore the thermal shutdown function should not be used for a system design.

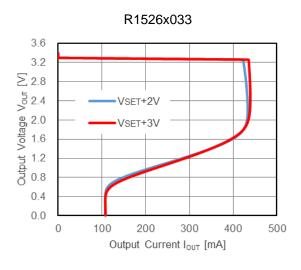
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# **TYPICAL CHARACTERISTICS**

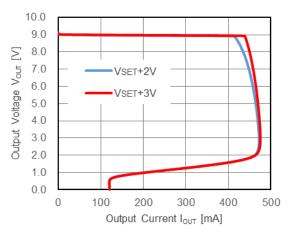
Note: Typical Characteristics are intended to be used as reference data; they are not guaranteed.



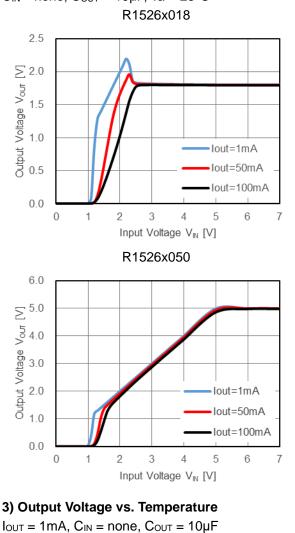






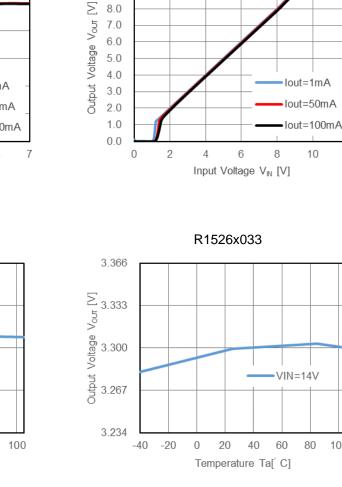


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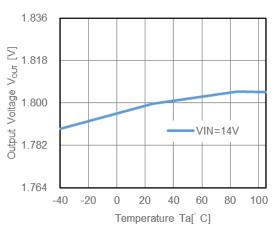


2) Output Voltage vs. Input Voltage

 $C_{IN}$  = none,  $C_{OUT}$  = 10µF, Ta = 25°C



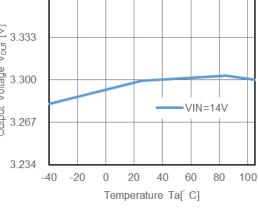
R1526x018



3.0 Output Voltage Voc [V] lout=1mA lout=50mA 0.5 lout=100mA 0.0 5 0 1 2 3 4 6 7 Input Voltage V<sub>IN</sub> [V] R1526x090 10.0 9.0 8.0 7.0 6.0 5.0 lout=1mA lout=50mA

R1526x033

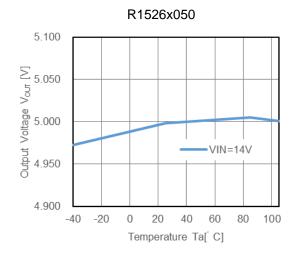
3.5

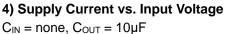


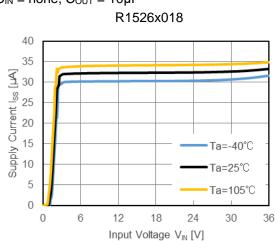
**RICOH** 

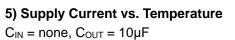
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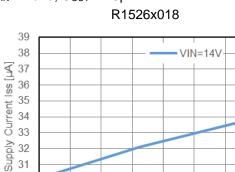
30

29

-40

-20

0



20

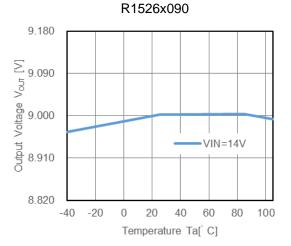
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Temperature Ta [° C]

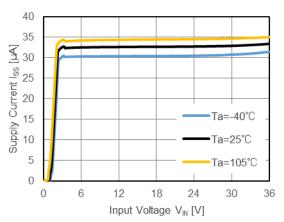
60

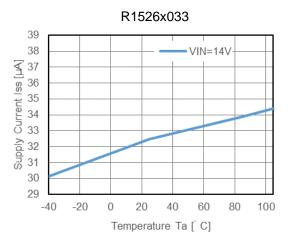
80

100









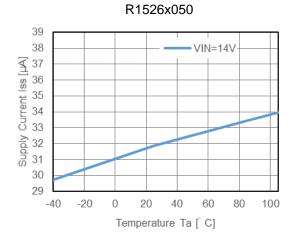
RICOH

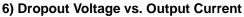
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VIN=14V

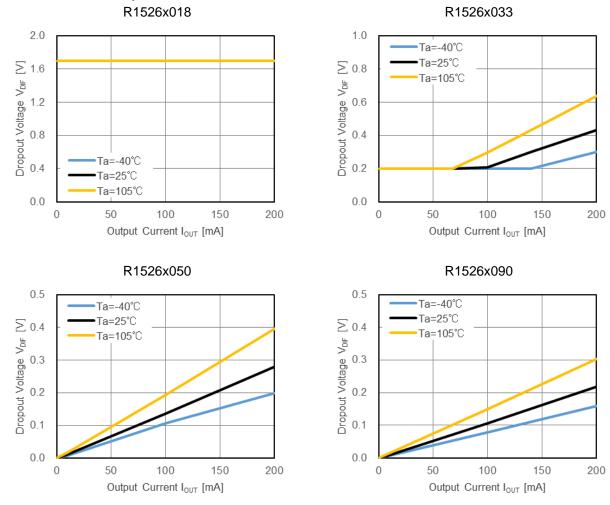
80

100





 $C_{IN} = none, C_{OUT} = 10 \mu F$ 



**RICOH** 

-20 0 20 40 60

Temperature Ta [° C]

R1526x090

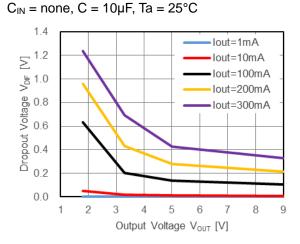
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38

30 29

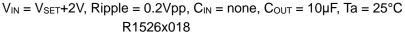
-40

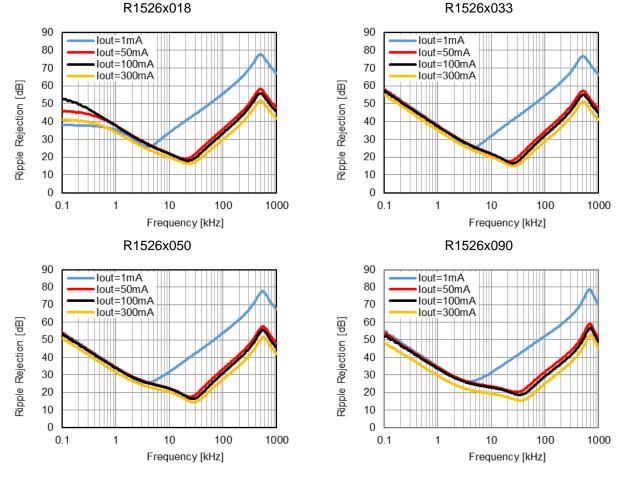
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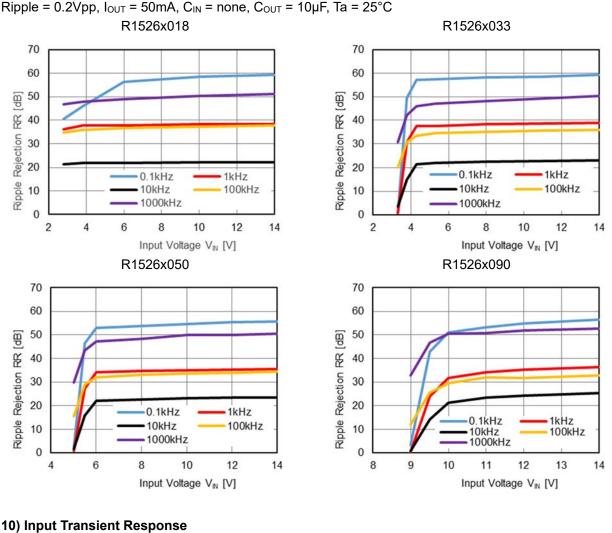
# 7) Dropout Voltage vs. Output Voltage





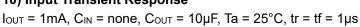


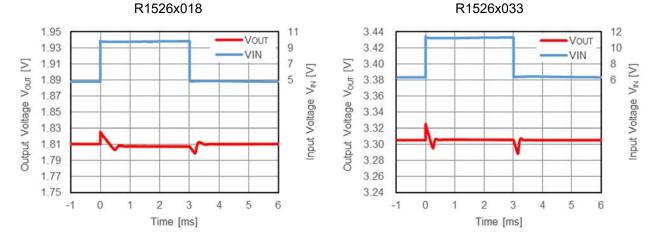
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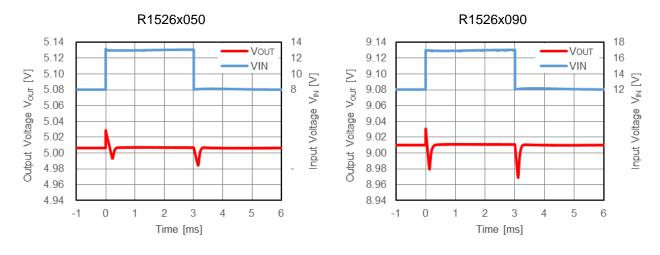
#### 9) Ripple Rejection vs. Input Voltage

Ripple = 0.2Vpp, I<sub>OUT</sub> = 50mA, C<sub>IN</sub> = none, C<sub>OUT</sub> = 10µF, Ta = 25°C

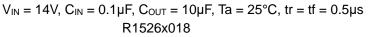




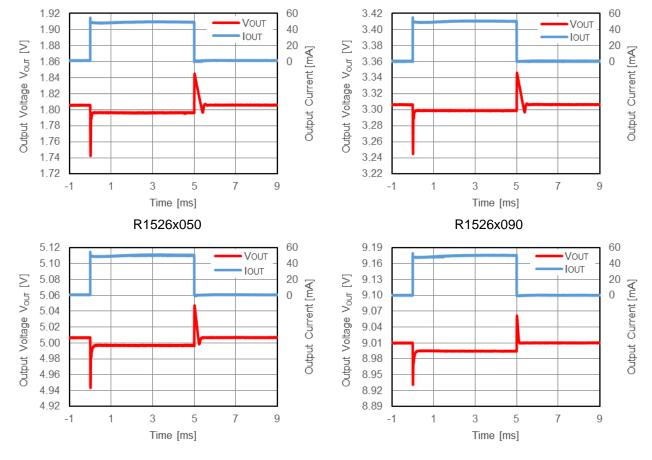
No. EA-527-201014



# 11) Load Transient Response

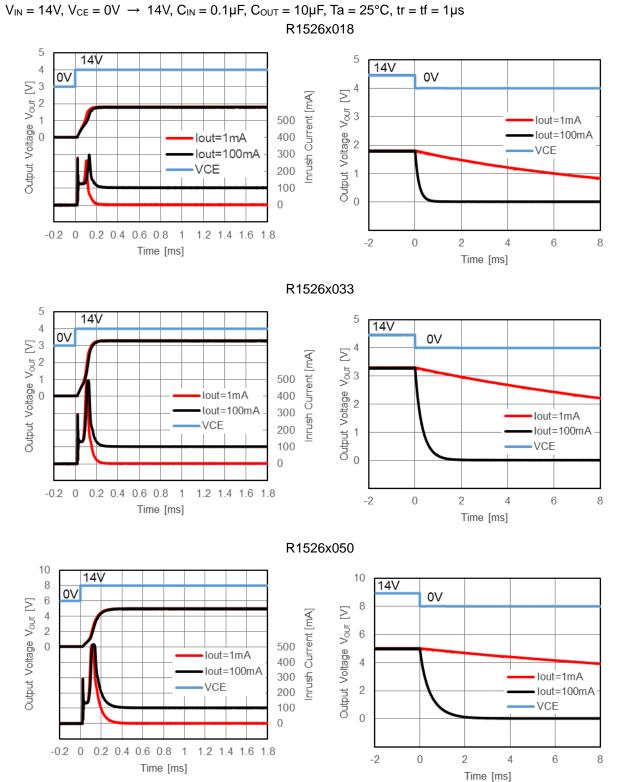






No. EA-527-201014

## 12) CE Transient Response

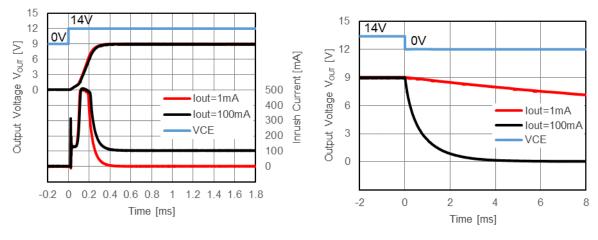


R1526x

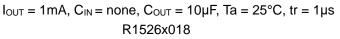
No. EA-527-201014

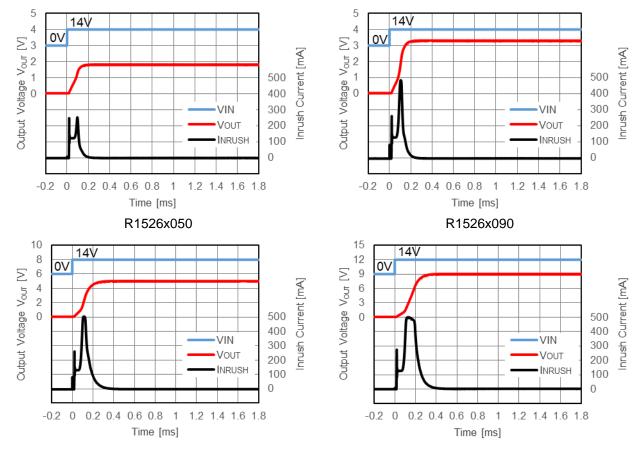
R1526x033



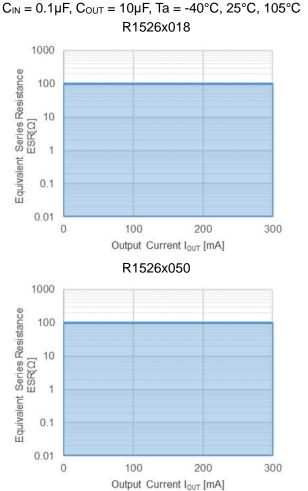


## 13) Power-on Transient Response

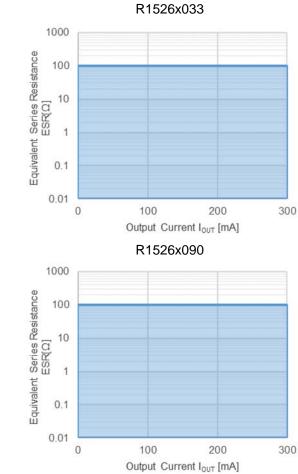




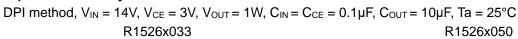
No. EA-527-201014

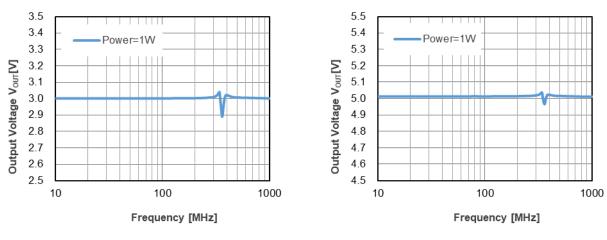


# 14) ESR (Equivalent Series Resistance)



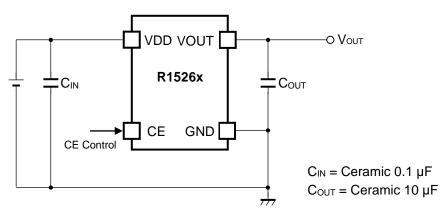
#### 15) Noise Immunity





No. EA-527-201014

# **Test Circuit**



# **Test Circuit for Typical Characteristics**

# **Measurement Components**

Symbol	Specification	Measurement Item	Manufacturer	Parts Number
CIN	0.1µF	11,12,14,15	TDK	CGA4J2X7R1H104K
Соит	10µF	All Items	TDK	CGA4J1X7S1C106K

**Measurement Components of Typical Characteristics** 

# **POWER DISSIPATION**

# **HSOP-8E**

PD-HSOP-8E-(105125)-JE-A

The power dissipation of the package is dependent on PCB material, layout, and environmental conditions. The following measurement conditions are based on JEDEC STD. 51-7.

#### **Measurement Conditions**

ltem	Measurement Conditions	
Environment	Mounting on Board (Wind Velocity = 0 m/s)	
Board Material	Glass Cloth Epoxy Plastic (Four-Layer Board)	
Board Dimensions	76.2 mm × 114.3 mm × 0.8 mm	
Copper Ratio	Outer Layer (First Layer): Less than 95% of 50 mm Square Inner Layers (Second and Third Layers): Approx. 100% of 50 mm Square Outer Layer (Fourth Layer): Approx. 100% of 50 mm Square	
Through-holes	φ 0.3 mm × 21 pcs	

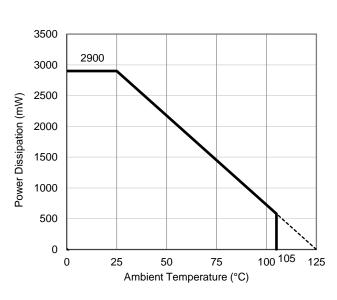
#### **Measurement Result**

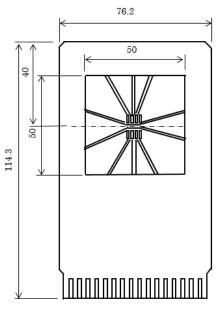
(Ta = 25°C, Tjmax = 125°C)

Item	Measurement Result
Power Dissipation	2900 mW
Thermal Resistance (θja)	θja = 34.5°C/W
Thermal Characterization Parameter (ψjt)	ψjt = 10°C/W

 $\theta$ ja: Junction-to-ambient thermal resistance.

wjt: Junction-to-top of package thermal characterization parameter



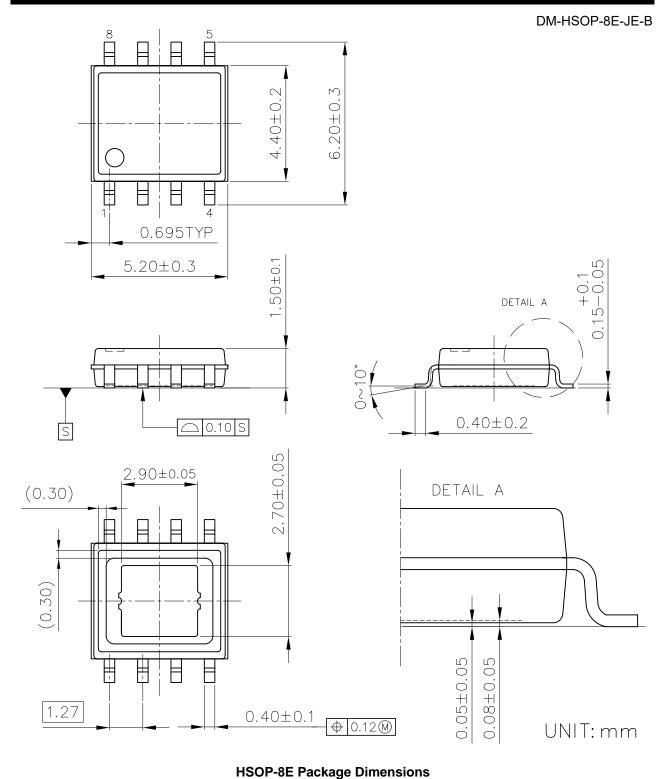


#### Power Dissipation vs. Ambient Temperature

**Measurement Board Pattern** 

# PACKAGE DIMENSIONS

# HSOP-8E



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